EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	12640	electrode same semiconductor and (germanium or round near3 edge)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:43
L2	2597	electrode same semiconductor same (germanium or round near3 edge)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:43
L3	3	electrode same semiconductor same (germanium and round near3 edge)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:45
L4	17	electrode same semiconductor same (fast adj comparator or fuse adj link$3)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 14:27
L5	19	electrode same semiconductor and ("temperature sensitive" near3 diode)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 13:54
L6	0	4 and 5	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:46
L7	0	thermocycl$4 and ("temperature sensitive" near3 diode)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:47
L8	0	thermocycl$4 and ("temperature sensitive" near8 diode)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:47
L9	0	2 and 5	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:53
L10	1	2 and 4	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 12:55
L11	21	fast near2 comparator adj circuit	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 13:46
L12	1	11 and temperature near2 sensitiv$4	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 13:46
L13	5	11 and temperature	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 13:46
L15	15	5 and resistan$5	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 13:55
L16	1	electrode same semiconductor same (fast adj comparator)	US-PGPUB; USPAT; DERWENT	OR	ON	2006/06/16 14:27

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S8	28	((RANDALL) near2 (DAVIS)).INV.	US-PGPUB; USPAT	OR	ON	2006/06/15 14:41
S9	33	((RANDALL) near2 (DAVIS)).INV.	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:00
S10	5	S9 not S8	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:03
S11	20987	semiconductor and electrodes same ((matrix or plurality) and (gap or space))	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:04
S12	290	S11 and electrodes same (probe or biomolecule or oligonucleotide or dna) near5 (attach$4 or fix$4 or afix$4 or immobiliz$4)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:06
S13	149	S12 and electrodes same gap	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:10
S14	5	S13 and eichen.in.	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:14
S15	114	S13 and (temperature and measur$4)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:15
S16	104	S15 and silicon	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:15
S17	15	S16 and germanium	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:16
S18	40	S16 and ("silicon dioxide" or sio2)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:16
S19	28	S16 and ("silicon dioxide" or sio2) same (layer$4 or coat$$ or insulat$5)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:27
S20	7	S17 and S19	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:17
S21	1	S19 and S14	US-PGPUB; USPAT; EPO	OR	ON	2006/06/15 15:28
S22	20987	semiconductor and electrodes same ((matrix or plurality) and (gap or space))	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 06:47

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S23	290	S22 and electrodes same (probe or biomolecule or oligonucleotide or dna) near5 (attach$4 or fix$4 or afix$4 or immobiliz$4)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 06:47
S24	149	S23 and electrodes same gap	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 06:47
S25	114	S24 and (temperature and measur$4)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 06:47
S26	104	S25 and silicon	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 06:47
S27	28	S26 and ("silicon dioxide" or sio2) same (layer$4 or coat$$ or insulat$5)	US-PGPUB; USPAT; EPO	OR	ON	2006/06/16 07:42